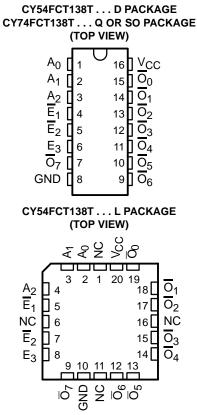
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- Function, Pinout, and Drive Compatible With FCT and F Logic
- Reduced V_{OH} (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- Dual 1-of-8 Decoder With Enables
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- CY54FCT138T
 - 32-mA Output Sink Current
 - 12-mA Output Source Current
- CY74FCT138T
 - 64-mA Output Sink Current
 - 32-mA Output Source Current



NC - No internal connection

description

The 'FCT138T devices are 1-of-8 decoders. These devices accept three binary weighted inputs (A₀, A₁, A₂) and, when enabled, provide eight mutually exclusive active-low outputs (\overline{O}_0 – \overline{O}_7). The 'FCT138T devices feature three enable inputs: two active low (\overline{E}_1 , \overline{E}_2) and one active high (E_3).

All outputs are high unless \overline{E}_1 and \overline{E}_2 are low and E_3 is high. This multiple-enable function allows easy parallel expansion of the device to a 1-of-32 (five lines to 32 lines) decoder with just four 'FCT138T devices and one inverter.

These devices are fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

	PIN DESCRIPTION
NAME	DESCRIPTION
А	Address inputs
$\overline{E}_1, \overline{E}_2$	Enable inputs (active low)
E ₃	Enable input (active high)
Ō	Outputs

DIN DESCRIPTION



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Copyright © 2001, Texas Instruments Incorporated On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

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ORDERING INFORMATION SPEED TOP-SIDE ORDERABLE PACKAGE[†] TA PART NUMBER MARKING (ns) QSOP - Q 5 CY74FCT138CTQCT FT138-3 Tape and reel 5 Tube CY74FCT138CTSOC SOIC - SO FCT138C 5 CY74FCT138CTSOCT Tape and reel –40°C to 85°C QSOP – Q Tape and reel 5.8 CY74FCT138ATQCT FT138-1 CY74FCT138ATSOC Tube 5.8 SOIC - SO FCT138A Tape and reel 5.8 CY74FCT138ATSOCT QSOP – Q Tape and reel 9 CY74FCT138TQCT FT138 LCC – L Tube 6 CY54FCT138CTLMB –55°C to 125°C LCC – L Tube 12 CY54FCT138TLMB CDIP – D Tube 12 CY54FCT138TDMB

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

		INP	UTS						OUTI	PUTS			
Ē ₁	E ₂	E3	A ₀	A ₁	A ₂	00	0 ₁	0 ₂	<u>0</u> 3	04	05	0 ₆	<u>0</u> 7
н	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
х	н	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	н
х	Х	L	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	н
L	L	Н	L	L	L	L	Н	Н	Н	Н	Н	Н	Н
L	L	н	н	L	L	н	L	Н	н	н	н	н	н
L	L	н	L	н	L	н	н	L	н	н	н	н	н
L	L	Н	Н	Н	L	н	Н	Н	L	Н	Н	Н	н
L	L	Н	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н
L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	н
L	L	Н	L	Н	Н	н	Н	Н	Н	Н	Н	L	н
L	L	Н	Н	Н	Н	н	Н	Н	Н	Н	Н	Н	L

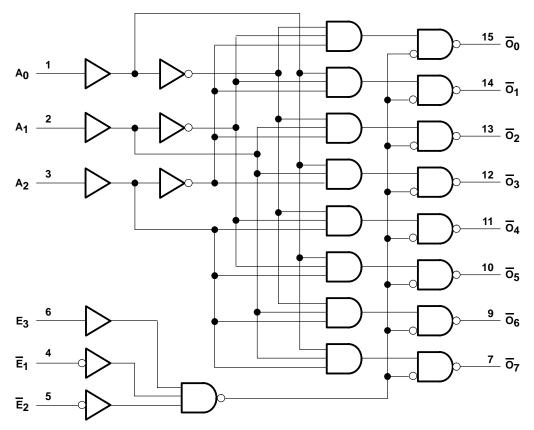
FUNCTION TABLE

H = High logic level, L = Low logic level, X = Don't care



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logic diagram (positive logic)



Pin numbers shown are for the D, Q, and SO packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range to ground potential	–0.5 V to 7 V
DC input voltage range	–0.5 V to 7 V
DC output voltage range	. –0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ _{JA} (see Note 1): Q package	90°C/W
SO package	57°C/W
Ambient temperature range with power applied, T _A	–65°C to 135°C
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.



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recommended operating conditions (see Note 2)

		CY	54FCT13	8T	CY	74FCT13	8T	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
ЮН	High-level output current			-12			-32	mA
IOL	Low-level output current			32			64	mA
Τ _Α	Operating free-air temperature	-55		125	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAD AMETER		C	(54FCT13	88T	CY	74FCT13	88T	
PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	MIN	түр†	MAX	UNIT
Maria	V _{CC} = 4.5 V, I _{IN} = -18 mA		-0.7	-1.2			-	v
VIK	V _{CC} = 4.75 V, I _{IN} = -18 mA					-0.7	-1.2	v
	$V_{CC} = 4.5 \text{ V}, \qquad I_{OH} = -12 \text{ mA}$	2.4	3.3					
VOH	V _{CC} = 4.75 V				2			V
	$I_{OH} = -15 \text{ mA}$				2.4	3.3		
VOL	$V_{CC} = 4.5 V$, $I_{OL} = 32 mA$		0.3	0.55				v
VOL	$V_{CC} = 4.75 \text{ V}, \qquad I_{OL} = 64 \text{ mA}$					0.3	0.55	v
V _{hys}	All inputs		0.2			0.2		V
6	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} = V_{CC}$			5				μA
łı	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} = V_{CC}$						5	μΛ
I	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} = 2.7 \text{ V}$			±1				μA
ЧН	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} = 2.7 \text{ V}$						±1	μΑ
١L	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} = 0.5 \text{ V}$			±1				μA
ЧL	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} = 0.5 \text{ V}$						±1	μΛ
los‡	V _{CC} = 5.5 V, V _{OUT} = 0 V	-60	-120	-225				mA
IOS+	V _{CC} = 5.25 V, V _{OUT} = 0 V				-60	-120	-225	
l _{off}	V _{CC} = 0 V, V _{OUT} = 4.5 V			±1			±1	μA
ICC	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} \leq 0.2 \text{ V}, \qquad V_{IN} \geq V_{CC} - 0.2 \text{ V}$		0.1	0.2				mA
	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} \leq 0.2 \text{ V}, \qquad V_{IN} \geq V_{CC} - 0.2 \text{ V}$		_			0.1	0.2	110.4
∆ICC	V_{CC} = 5.5 V, V_{IN} = 3.4 V§, f ₁ = 0, Outputs open		0.5	2				mA
aicc	V_{CC} = 5.25 V, V_{IN} = 3.4 V§, f ₁ = 0, Outputs open					0.5	2	
	V_{CC} = 5.5 V, Outputs open, One bit switching at 50% duty cycle, V_{IN} \leq 0.2 V or V_{IN} \geq V_{CC} – 0.2 V		0.06	0.12				mA/
ICCD	V_{CC} = 5.25 V, Outputs open, One bit switching at 50% duty cycle, V_{IN} \leq 0.2 V or V_{IN} \geq V_{CC} – 0.2 V					0.06	0.12	MHz

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

* Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

§ Per TTL-driven input (V_{IN} = 3.4 V); all other inputs at V_{CC} or GND

This parameter is derived for use in total power-supply calculations.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

DADAMETER		TEST CONDITION	10	CY	54FCT13	8T	CY	74FCT13	8T	
PARAMETER			15	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
	$V_{CC} = 5.5 V$, Outputs open, Switch \overline{E}_1 , \overline{E}_2 , or	One output switching at f ₁ = 10 MHz	$\begin{array}{l} V_{IN} \leq 0.2 \ V \ or \\ V_{IN} \geq V_{CC} - 0.2 \ V \end{array}$		0.7	1.4				
IC#	E ₃	at 50% duty cycle	V_{IN} = 3.4 V or GND		1	2.4				mA
	$V_{CC} = 5.25 V,$ Outputs open, Switch E_1, E_2 , or	One output switching at f ₁ = 10 MHz	$\begin{array}{l} V_{IN} \leq 0.2 \ V \ \text{or} \\ V_{IN} \geq V_{CC} - 0.2 \ V \end{array}$					0.7	1.4	
	E_3	at 50% duty cycle	V_{IN} = 3.4 V or GND					1	2.4	
Ci					5	10		5	10	pF
Co					9	12		9	12	pF

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

 ${}^{\#}IC = ICC + \Delta ICC \times DH \times NT + ICCD (f_0/2 + f_1 \times N_1)$

Where:

IC = Total supply current

ICC = Power-supply current with CMOS input levels

 ΔI_{CC} = Power-supply current for a TTL high input (V_{IN} = 3.4 V)

 D_H = Duty cycle for TTL inputs high

 N_T = Number of TTL inputs at D_H

 I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

- f_0 = Clock frequency for registered devices, otherwise zero
- f_1 = Input signal frequency

 N_1 = Number of inputs changing at f_1

All currents are in milliamperes and all frequencies are in megahertz.

I Values for these conditions are examples of the I_{CC} formula.

switching characteristics over operating free-air temperature range (see Figure 1)

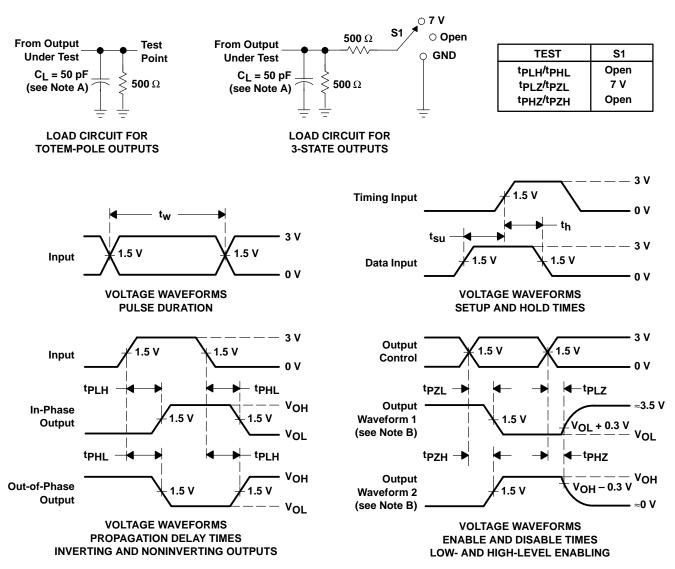
PARAMETER	FROM	то	CY54FC	T138T	CY54FC	Г138СТ	UNIT
FARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
^t PLH	А	ō	1.5	12	1.5	6	ns
^t PHL	Ϋ́,	0	1.5	12	1.5	6	115
^t PLH		ō	1.5	12.5	1.5	6.1	ns
^t PHL	\overline{E}_1 or \overline{E}_2	0	1.5	12.5	1.5	6.1	115
^t PLH	Ea	ō	1.5	12.5	1.5	6.1	
^t PHL	E3	0	1.5	12.5	1.5	6.1	ns

switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	CY74FC	T138T	CY74FC1	138AT	CY74FC1	138CT	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	А	ō	1.5	9	1.5	5.8	1.5	5	ns
^t PHL	Α.	0	1.5	9	1.5	5.8	1.5	5	115
^t PLH		ō	1.5	9	1.5	5.9	1.5	5	
^t PHL	\overline{E}_1 or \overline{E}_2	0	1.5	9	1.5	5.9	1.5	5	ns
^t PLH	Ea	ō	1.5	9	1.5	5.9	1.5	5	
tPHL	E3	0	1.5	9	1.5	5.9	1.5	5	ns



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





25-Sep-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty		Lead/Ball Finish	•	Op Temp (°C)	Device Marking	Samples
5962-9223302M2A	(1) ACTIVE	LCCC	FK	20	1	(2) TBD	POST-PLATE	⁽³⁾ N / A for Pkg Type	-55 to 125	(4/5) 5962- 9223302M2A CY54FCT 138TLMB	Samples
5962-9223302MEA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9223302ME A CY54FCT138TDMB	Samples
5962-9223306M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9223306M2A CY54FCT 138CTLMB	Samples
5962-9223306MEA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9223306ME A	Samples
CY54FCT138CTLMB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9223306M2A CY54FCT 138CTLMB	Samples
CY54FCT138TDMB	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9223302ME A CY54FCT138TDMB	Samples
CY54FCT138TLMB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9223302M2A CY54FCT 138TLMB	Samples
CY74FCT138ATQCT	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT138-1	Samples
CY74FCT138ATQCTE4	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT138-1	Samples
CY74FCT138ATQCTG4	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT138-1	Samples
CY74FCT138ATSOC	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT138A	Samples
CY74FCT138ATSOCE4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT138A	Samples
CY74FCT138ATSOCG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT138A	Samples



PACKAGE OPTION ADDENDUM

25-Sep-2013

Orderable Device	Status	Package Type		Pins		Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
CY74FCT138ATSOCT	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT138A	Samples
CY74FCT138ATSOCTE4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT138A	Samples
CY74FCT138ATSOCTG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT138A	Samples
CY74FCT138CTQCT	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT138-3	Samples
CY74FCT138CTQCTE4	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT138-3	Samples
CY74FCT138CTQCTG4	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT138-3	Samples
CY74FCT138CTSOC	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT138C	Samples
CY74FCT138CTSOCE4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT138C	Samples
CY74FCT138CTSOCG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT138C	Samples
CY74FCT138TQCT	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT138	Samples
CY74FCT138TQCTE4	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT138	Samples
CY74FCT138TQCTG4	ACTIVE	SSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT138	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.



PACKAGE OPTION ADDENDUM

25-Sep-2013

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above. Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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PACKAGE MATERIALS INFORMATION

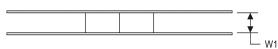
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT138ATSOCT	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT138ATSOCT	SOIC	DW	16	2000	367.0	367.0	38.0

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